

BD933; 935
BD937; 939
BD941

PHILIPS INTERNATIONAL

56E D

7110826 0043044 416 PHIN

SILICON EPITAXIAL BASE POWER TRANSISTORS

T-33-09

N-P-N silicon transistors in a plastic envelope intended for use in output stages of audio and television amplifier circuits where high peak powers can occur.

P-N-P complements are BD934; 936; 938; 940 and 942.

QUICK REFERENCE DATA

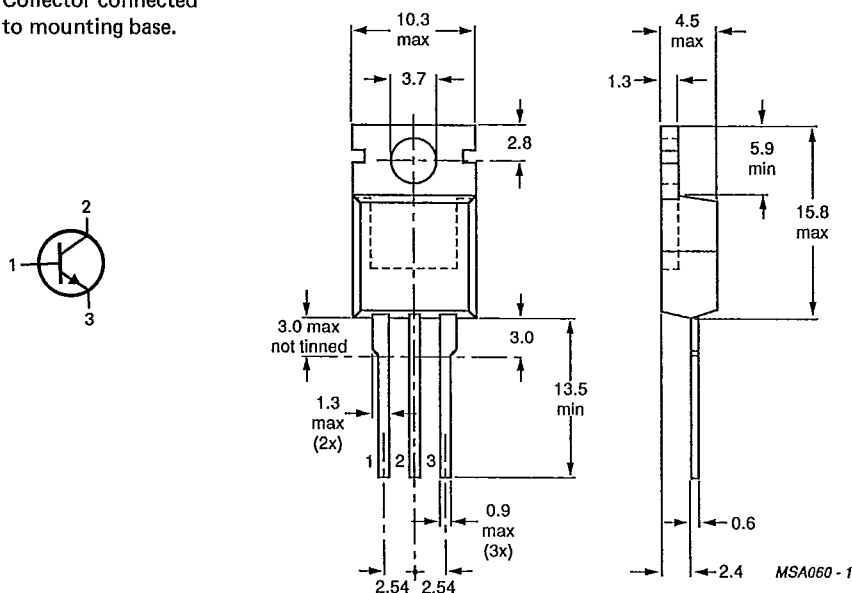
			BD933	935	937	939	941
Collector-base voltage	V_{CBO}	max.	45	60	100	120	140 V
Collector-emitter voltage	V_{CEO}	max.	45	60	80	100	120 V
Collector current (d.c.)	I_C	max.			3		A
Total power dissipation up to $T_{mb} = 25^\circ\text{C}$	P_{tot}	max.			30		W
Junction temperature	T_j	max.			150		$^\circ\text{C}$
D.C. current gain							
$I_C = 150\text{ mA}; V_{CE} = 2\text{ V}$	h_{FE}				40 to 250		
$I_C = 1\text{ A}; V_{CE} = 2\text{ V}$	h_{FE}	>			25		
Transition frequency							
$I_C = 250\text{ mA}; V_{CE} = 10\text{ V}$	f_T	>			3		MHz

MECHANICAL DATA

Dimensions in mm

Fig. 1 TO-220.

Collector connected to mounting base.



See also chapters Mounting instructions and Accessories.

BD933; 935
BD937; 939
BD941

PHILIPS INTERNATIONAL

56E D ■ 7110826 0043045 352 ■ PHIN

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

T-33-09

			BD933	935	937	939	941
Collector-base voltage (open emitter)	V_{CBO}	max.	45	60	100	120	140 V
Collector-emitter voltage (open base)	V_{CEO}	max.	45	60	80	100	120 V
Emitter-base voltage (open collector)	V_{EBO}	max.			5		V
Collector current (d.c.)	I_C	max.			3		A
Collector current (peak value)	I_{CM}	max.			7		A
Base current (d.c.)	I_B	max.			0,5		A
Total power dissipation up to $T_{mb} = 25\text{ }^{\circ}\text{C}$	P_{tot}	max.			30		W
Storage temperature	T_{stg}				-65 to + 150		$^{\circ}\text{C}$
Junction temperature	T_j	max.			150		$^{\circ}\text{C}$

THERMAL RESISTANCE

From junction to mounting base	$R_{th\ j-mb}$	=		4,17		K/W
From junction to ambient in free air	$R_{th\ j-a}$	=		70		K/W

CHARACTERISTICS

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

Collector cut-off current

$I_E = 0; V_{CB} = V_{CBOmax}$ $I_{CBO} < 50\text{ }\mu\text{A}$

$I_E = 0; V_{CB} = V_{CBOmax}; T_j = 150\text{ }^{\circ}\text{C}$ $I_{CBO} < 1\text{ mA}$

$I_E = 0; V_{CE} = V_{CEOmax}$ $I_{CEO} < 0,1\text{ mA}$

Emitter cut-off current

$I_C = 0; V_{EB} = 5\text{ V}$ $I_{EBO} < 0,2\text{ mA}$

D.C. current gain *

$I_C = 150\text{ mA}; V_{CE} = 2\text{ V}$ $h_{FE} 40\text{ to }250$

$I_C = 1\text{ A}; V_{CE} = 2\text{ V}$ $h_{FE} > 25$

Base-emitter voltage **

$I_C = 1\text{ A}; V_{CE} = 2\text{ V}$ $V_{BE} < 1,3\text{ V}$

Collector-emitter saturation voltage *

$I_C = 1\text{ A}; I_B = 0,1\text{ A}$ $V_{CEsat} < 0,6\text{ V}$

Transition frequency at $f = 1\text{ MHz}$

$I_C = 250\text{ mA}; V_{CE} = 10\text{ V}$ $f_T > 3\text{ MHz}$

Switching times

$I_{Con} = 1\text{ A}; I_{Bon} = -I_{Boff} = 0,1\text{ A}$ $t_{on} \text{ typ. } 0,4\text{ }\mu\text{s}$

turn-on time $t_{on} < 1\text{ }\mu\text{s}$

Turn-off time $t_{off} \text{ typ. } 1,5\text{ }\mu\text{s}$

$t_{off} < 3\text{ }\mu\text{s}$

Second-breakdown collector current

$V_{CE} = 40\text{ V}; t_p = 0,1\text{ s}; \text{non-repetitive}$ $I_{(SB)} > 0,75\text{ A}$

* Measured under pulse conditions: $t_p \leq 300\text{ }\mu\text{s}$; $\delta < 2\%$.

** V_{BE} decreases by about 2,3 mV/K with increasing temperature.

PHILIPS INTERNATIONAL

56E D

7277499.5

7110826 0043046 299 PHIN

T-33-09

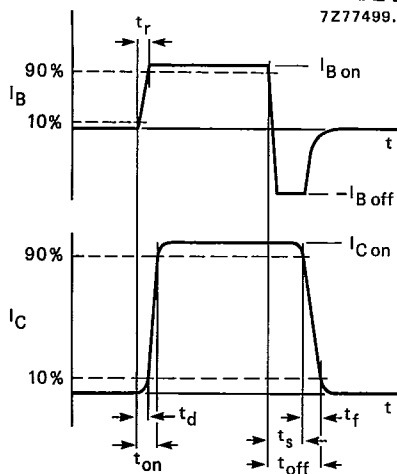


Fig. 2 Switching times waveforms.

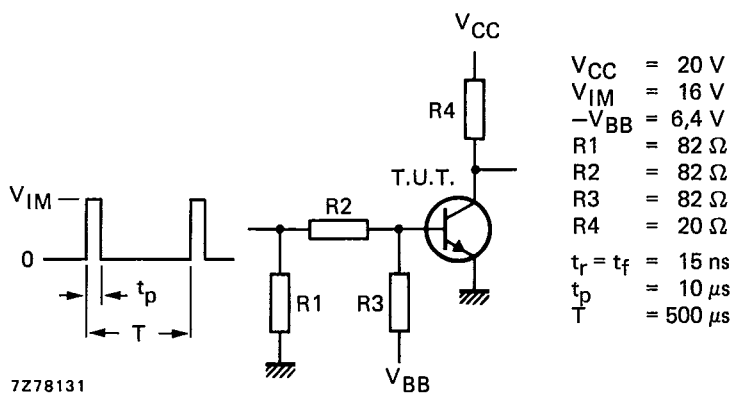


Fig. 3 Switching times test circuit.

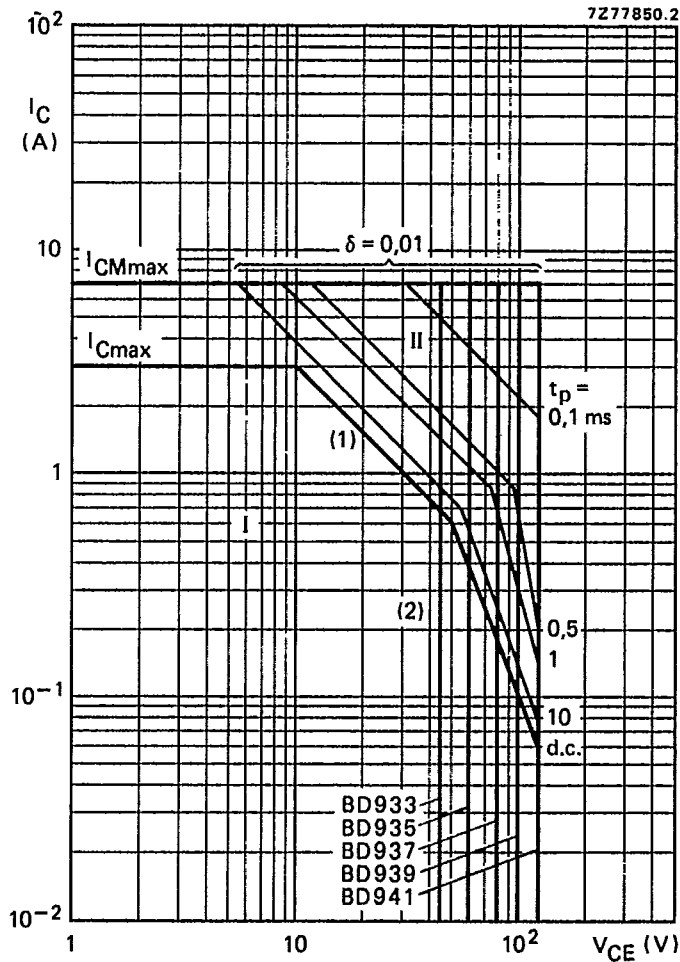


Fig. 4 Safe Operating Area, $T_{mb} = 25^\circ\text{C}$.

- I Region of permissible d.c. operation.
- II Permissible extension for repetitive pulse operation.
- (1) $P_{tot \text{ max}}$ and $P_{peak \text{ max}}$ lines.
- (2) Second-breakdown limits.

PHILIPS INTERNATIONAL

56E D

7110826 0043048 061 PHIN

7Z82178

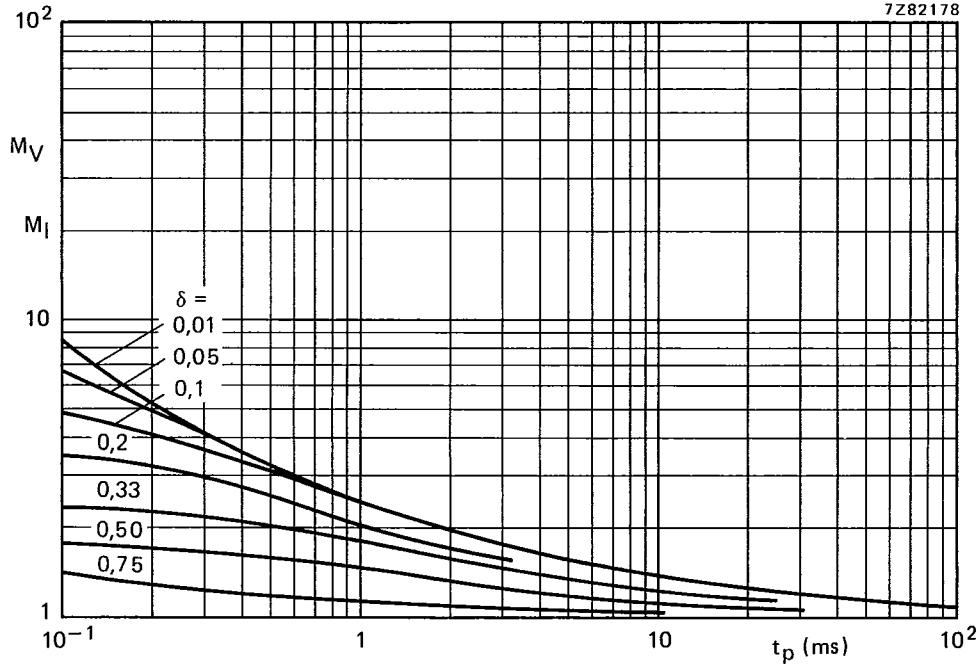


Fig. 5 Second-breakdown voltage multiplying factor at the I_{Cmax} level and second-breakdown current multiplying factor at the V_{CE0max} level.

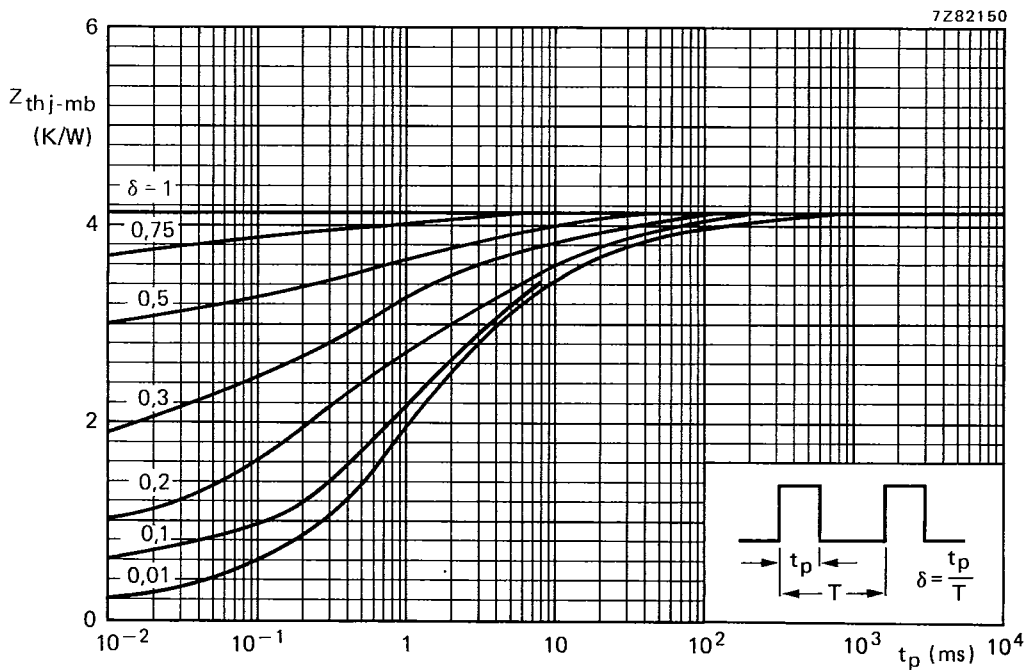


Fig. 6 Pulse power rating chart.

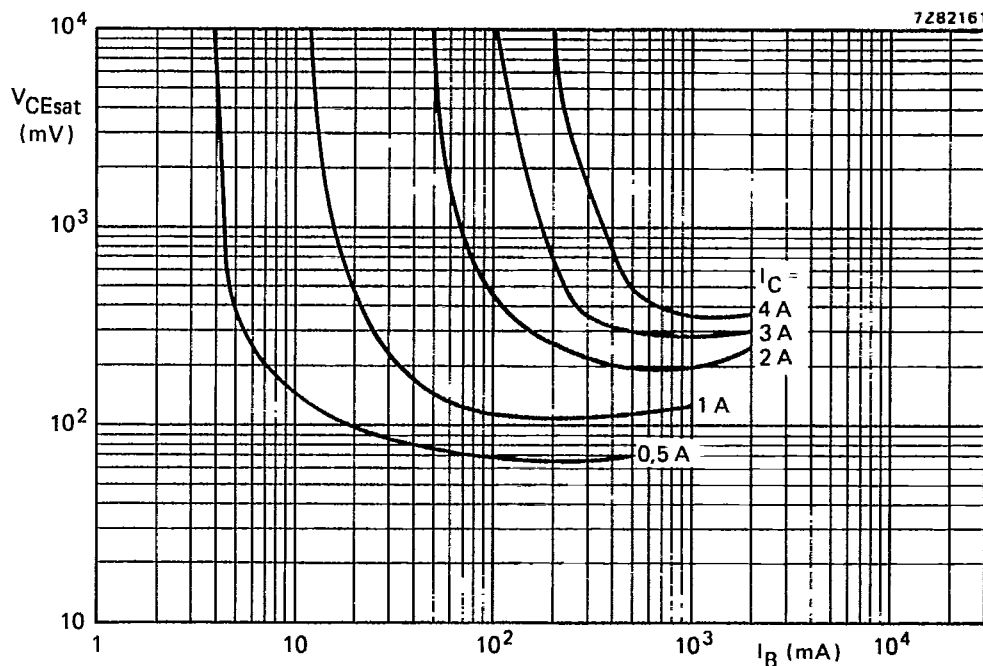


Fig. 7 Typical collector-emitter saturation voltage as a function of base current with collector current as a parameter.

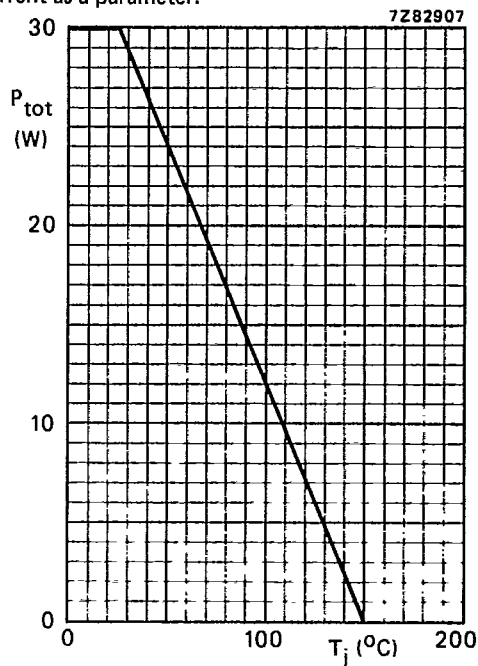


Fig. 8 Power derating curve.

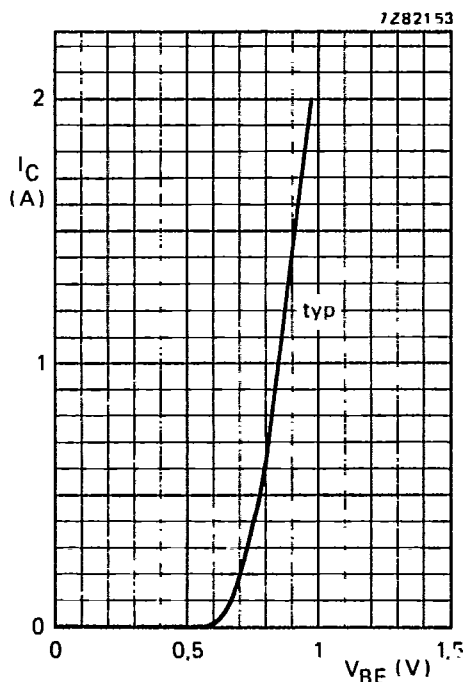


Fig. 9 $V_{CE} = 2$ V; $T_j = 25^{\circ}C$.

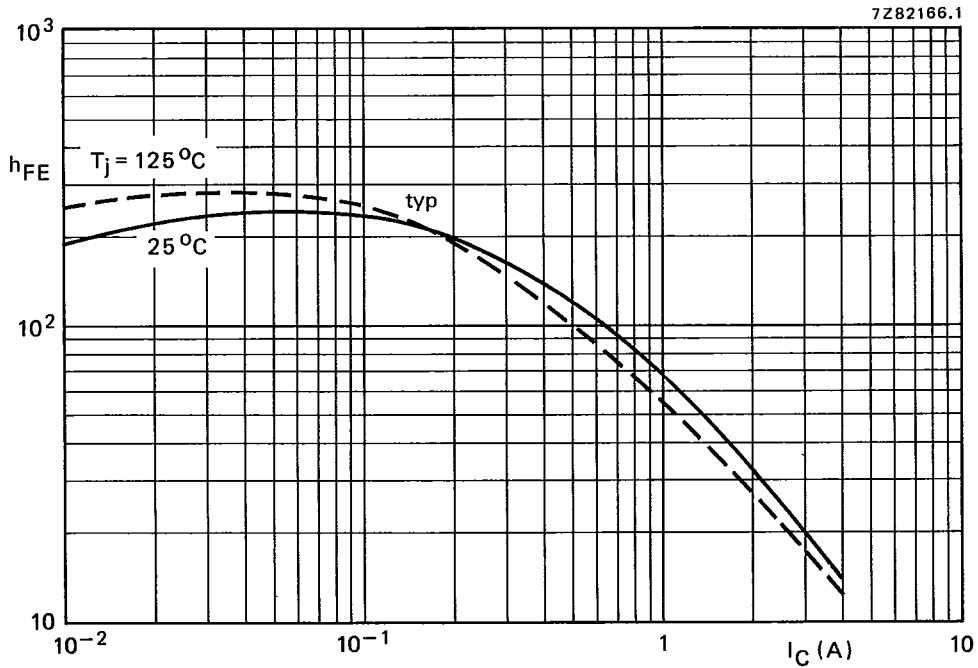


Fig. 10 Typical static forward current transfer ratio as a function of the collector current. $V_{CE} = 2$ V